

## IMPROVING EMI ATTENUATION IN FREQUENCY MODULATED POWER CONVERTERS

### ELEKTROMAGNĒTISKO TRAUCĒJUMU UZLABOŠANA FREKVENČU MODULĒTOS IMPULSU PĀRVEIDOTĀJOS

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*Keywords: boost converter, frequency modulation, amplitude modulation, EMI attenuation, input current*

**Abstract** - The effect of frequency modulation on a power switching converter electromagnetic interference (EMI) attenuation is examined in this paper. A method known as “modified sawtooth” is applied for EMI attenuation in a boost converter and it is optimized in such a way to reduce EMI more effectively. The method is also verified experimentally by the use of a low power boost converter controlled via an arbitrary waveform generator. EMI attenuation up to 15 dB is achieved after using modified sawtooth modulating waveform.

#### Introduction

Electromagnetic interference (EMI) emission is always one of the major problems in the field of switching power converters (SPC) [1]. Various EMI reduction schemes have been proposed over the last decades [4,5]. The traditional techniques for mitigating the problems in SPC usually include the use of input EMI filters, shielding, proper design of printed circuit boards, soft switching techniques, etc [2]. Another successful approach for EMI reduction is based on modulating a parameter, such as the switching frequency in random or periodic manner [4]. As a result of this method, energy of discrete harmonics of unmodulated switching frequency is spread over a wider frequency range, thus significantly reducing peak EMI levels [2]. Despite the fact that random switching frequency modulation (SFM) is often used in many practical SPC because of better conducted EMI attenuation, periodic SFM have some advantages [2]. The problem with random methods is that EMI is equally spread along the whole frequency spectrum, i.e. such methods do not provide any control on the bands where EMI energy is spread, while periodic SFM do [2]. This feature is very important for certain applications such as cellular phones or automobile communications systems,

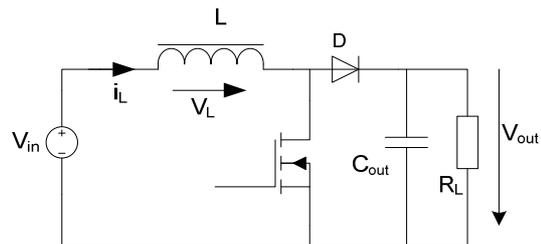
where EMI at certain selective frequencies must be avoided [2]. That is why periodic SFM is chosen to be used in this paper.

Input current amplitude modulation (AM) effects caused by frequency modulation are the major problem worsening attenuation of conducted EMI in frequency modulated DC-DC SPC [3] and electronic ballasts [10]. Although the method known as “modified ramp” was used to minimize AM effects in electronic ballasts [10], this method, first of all, is not applied to boost converters; secondly, it is not optimized for given values of modulation parameters to reduce EMI more effectively. So the main aim of the paper is, firstly, to analyze effect of FM on the boost converter EMI attenuation, secondly, to verify if this method is effective for EMI reduction in boost converters, and finally, to optimize this method for maximum EMI attenuation considering FM parameters.

#### Theoretical analysis

##### *Theoretical attenuation of modulated input current*

The boost DC-DC converter in Fig.1 is used for the analysis. Since discontinuous conduction mode (DCM) is less preferable for the boost converter (mainly due to worse EMI) [5], all the



**Fig.1** Basic schematics of the boost converter

calculations will be performed for continuous conduction mode (CCM). For the EMI performance of SPC the input current is of special interest, because it is responsible for conducted EMI. Therefore, the input current will be considered in this analysis.

For the boost converter inductor current  $i_L$  is equal to the input current. A basic equation for the inductor current is given by:

$$L \frac{di_L(t)}{dt} = V_L(t) \quad , \quad (1)$$

where  $V_L$  is the voltage across the inductor  $L$ .

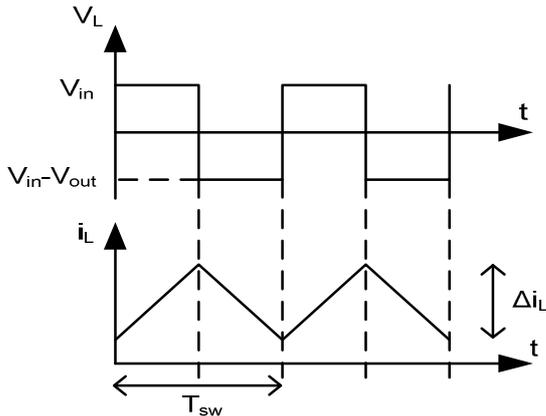
It is obvious that the inductor current from (1) is given by:

$$i_L(t) = I_L(0) + \frac{1}{L} \int_0^t V_L(t) dt \quad (2)$$

Fig.2 shows the corresponding waveforms for the inductor voltage and current. Directly from (2), peak-to-peak inductor current ripples  $\Delta i_L$  over one switching period  $T_{sw}$  can be calculated as follows [5]:

$$\Delta i_L = \frac{V_{in}}{L} DT_{sw} \quad , \quad (3)$$

where  $D$  is duty cycle.



**Fig.2** Theoretical unmodulated inductor current and voltage

Unmodulated inductor voltage spectrum of the converter consists of harmonics of switching frequency  $f_{sw}$ . When modulating the switching frequency, each individual harmonic is spread into a certain frequency band, thus reducing the peak

amplitudes of EMI spectrum [2,6] (see Fig.3). Resulting spectrum consists of sidebands that are symmetrical with respect to each unmodulated  $f_{sw}$  harmonic [6,8]. Furthermore, the sidebands consist of side frequencies, which are modulating frequency ( $f_m$ ) apart [4].

The worst situation for the boost converter from EMI point of view is when  $D=0.5$ , because all energy is concentrated in odd harmonics, so peak value is maximum [2,7].

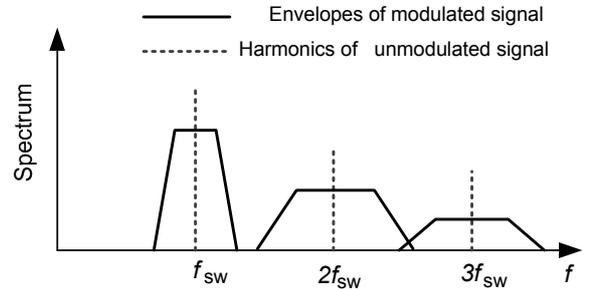
A general expression of frequency modulated inductor voltage for  $D=0.5$  is as follows:

$$s_m(t) = V_{in} \operatorname{sgn}[\cos(2\pi f_{sw}t + \theta(t))] \quad , \quad (4)$$

where  $\theta(t)$  is time dependent phase angle, according to [6]

$$\theta(t) = 2\pi \int_0^t k_f \cdot m(\tau) d\tau \quad , \quad (5)$$

where  $m(\tau)$  is a modulating waveform;  $k_f$  is the scaling coefficient of the frequency deviation  $\Delta f_{sw}$  at given amplitude  $A_m$  of a modulating waveform,  $k_f = \Delta f_{sw} / A_m$ .

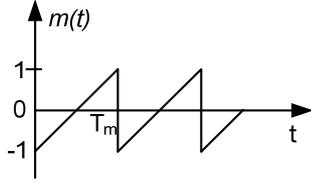


**Fig. 3** Simplified spectral structure of modulated and unmodulated inductor voltage

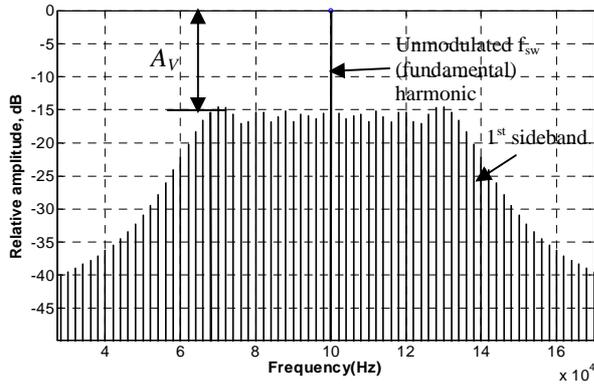
Suppression of high-order harmonics is more effective than low-order ones, so the fundamental harmonic attenuation is worse than that for other harmonics of  $f_{sw}$  [4]. That is why we will consider only the attenuation of the fundamental harmonic. The attenuation ( $A$ ) is the difference expressed in dB between maximum values of the unmodulated and modulated spectrum amplitude and is given by [8, 9]:

$$A = 20 \log_{10} \left( \frac{\max(|S_{unmod}(f)|)}{\max(|S_{mod}(f)|)} \right) \quad , \quad (6)$$

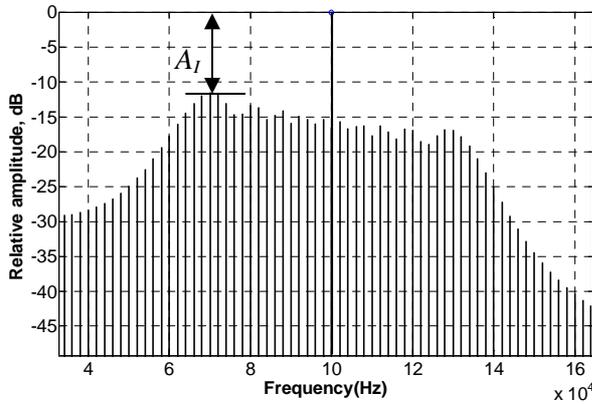
where  $S_{unmod}(f)$  is the spectrum of unmodulated signal;  $S_{mod}(f)$  is the spectrum of modulated signal. In present analysis, sawtooth modulating waveform (Fig.4) is used, because of its better EMI reduction potential compared with other waveforms, such as sinusoidal [8]. In order to get theoretical spectra for both modulated and unmodulated  $V_L$  and  $i_L$  numerical calculations in Matlab 7.5 are performed. Fig.5 depicts the calculated spectrum of frequency modulated



**Fig.4** Sawtooth modulating waveform



**Fig.5** Theoretical spectrum of modulated  $V_L$  (the 1<sup>st</sup> sideband only shown). Modulation parameters:  $\Delta f_{sw}=40\text{kHz}$ ,  $f_m=2\text{kHz}$ ,  $f_{sw}=100\text{kHz}$



**Fig.6** Theoretical spectrum of modulated  $i_L$  (the 1<sup>st</sup> sideband only shown). Modulation parameters:  $\Delta f_{sw}=40\text{kHz}$ ,  $f_m=2\text{kHz}$ ,  $f_{sw}=100\text{kHz}$

inductor voltage in relative values with respect to fundamental harmonic amplitude of unmodulated  $V_L$ . The spectrum amplitude reduction for  $V_L$  is derived as follows:

$$A_V = 20 \log_{10} (C_{1unmodV} / C_{maxV}(f_{max})), \quad (7)$$

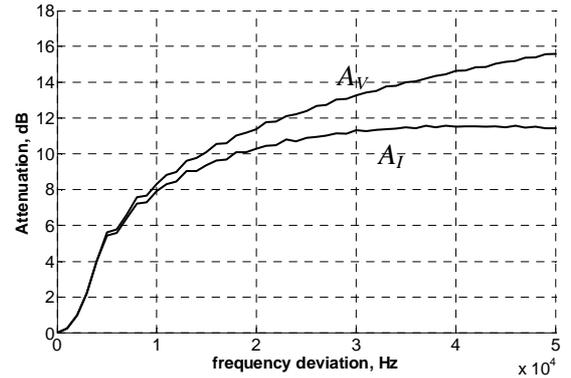
where  $C_{1unmodV}$  is the fundamental harmonic amplitude for unmodulated inductor voltage;  $C_{maxV}(f_{max})$  is the maximum amplitude of the harmonic of the 1<sup>st</sup> sideband at frequency  $f_{max}$ . Theoretical spectrum of  $i_L$  (Fig.6) can be calculated using spectrum of  $V_L$  and (2) as follows:

$$|S_{modI}(f)| = |S_{modV}(f)| / (2\pi f L), \quad (8)$$

where  $S_{modI}(f)$  is modulated inductor current spectrum;  $S_{modV}(f)$  is modulated inductor voltage spectrum. The theoretical attenuation  $A_I$  of maximum amplitude of unmodulated  $i_L$  spectrum is calculated using Matlab by the following expression:

$$A_I = 20 \log_{10} \left( \frac{\max |S_{unmodI}(f)|}{\max |S_{modI}(f)|} \right), \quad (9)$$

where  $S_{unmodI}(f)$  and  $S_{modI}(f)$  are unmodulated and modulated inductor current spectrum respectively. As a result, in Fig.7 the theoretical



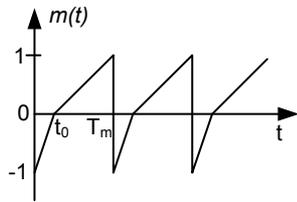
**Fig.7** Theoretical  $A_I$  and  $A_V$  as a function of  $\Delta f_{sw}$  for  $f_m=2\text{kHz}$

attenuation as a function of  $\Delta f_{sw}$  with  $f_m=2\text{kHz}$  is shown for both  $V_L$  and  $i_L$ . As we can see from this figure attenuation of maximum amplitude of  $V_L$  spectrum is increasing function of  $\Delta f_{sw}$ . However, it is not the case for  $i_L$ :  $A_I$  increases when changing  $\Delta f_{sw}$  up to 30 kHz, then it

becomes almost constant and after  $\Delta f_{sw} = 45\text{kHz}$  it decreases slightly. The difference between  $A_V$  and  $A_I$  is caused by amplitude modulation (AM) of the input current. The reason for AM effects is that inductor current ripples  $\Delta i_L$  are inversely proportional to switching frequency according to (3). In the frequency domain, AM effects result in spectrum distortion characterized by the spectrum asymmetry with respect to central switching frequency [10]. As a result, more energy is concentrated in the lower half of the sideband [10]. Despite the fact that for small  $\Delta f_{sw}$  AM effects are not pronounced appreciably, they must be reduced, because the higher  $\Delta f_{sw}$  is, the higher attenuation is.

### Improving EMI attenuation

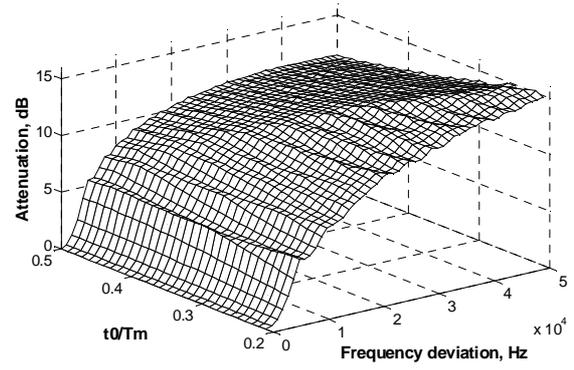
Analysis of Fig.5 and Fig.6 can give important information to minimize AM effects and improve the attenuation. Since more energy is concentrated in the lower half of the sideband of modulated input current spectrum, one should decrease length of time spent by modulating waveform in frequency range below the central switching frequency [10]. This can be done by using different slopes of modified sawtooth modulating waveform (Fig.8) for the lower and upper halves



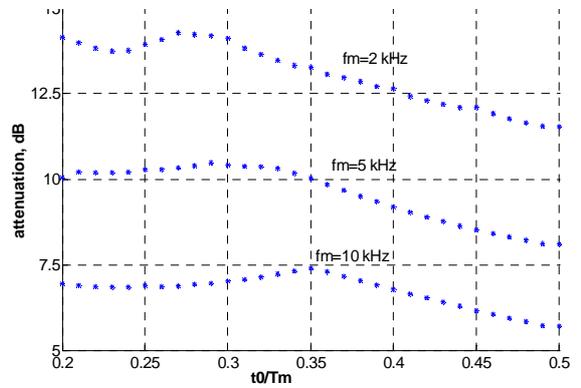
**Fig.8** Modified sawtooth modulating waveform

of the sideband [10]. The slopes are controlled by changing values of  $t_0$ .

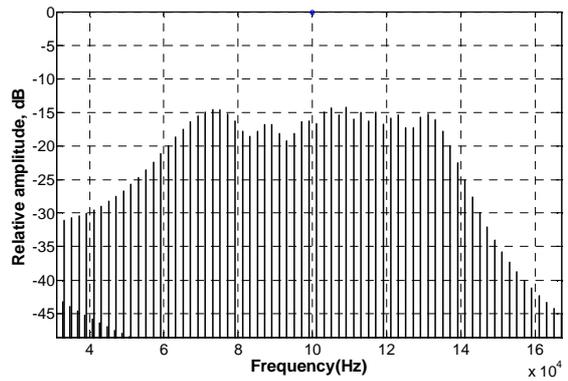
Despite the modified sawtooth is used also in [10] to reduce AM effects in electronic ballasts, there is no information how to choose  $t_0$  for optimum EMI attenuation taking in account FM parameters. In order to find the optimum values of  $t_0$  to get the best attenuation, numerical calculations in Matlab are again performed for the different values of  $f_m$ ,  $\Delta f_{sw}$  (in the range 0 – 50 kHz) and  $t_0$  (in the range  $0.2T_m - 0.5T_m$ ). As a result,  $A_I$  as a function of both  $\Delta f_{sw}$  and  $t_0$  for  $f_m = 2\text{kHz}$  is depicted in Fig.9 using Matlab mesh function.  $A_I$  as a function of  $t_0$  for different  $f_m$  but



**Fig.9** Theoretical  $A_I$  as a function of  $\Delta f_{sw}$  and  $t_0$  for  $f_m = 2\text{ kHz}$



**Fig.10** Theoretical  $A_I$  as a function of  $f_m$  and  $t_0$  for  $\Delta f_{sw} = 40\text{ kHz}$



**Fig.11** Theoretical spectrum of modulated  $i_L$  with modified modulating sawtooth waveform.

Modulation parameters:  $\Delta f_{sw} = 40\text{kHz}$ ,  $f_m = 2\text{kHz}$   
 $f_{sw} = 100\text{kHz}$ ,  $t_0 = 0.27T_m$

fixed  $\Delta f_{sw} = 40\text{kHz}$  is shown in Fig.10. Analysis of the figures can reveal some interesting facts. Firstly, the higher  $\Delta f_{sw}$  is, the lower  $t_0$  should be to minimize AM effects appreciably.

As it can be deduced from Fig.9 we can get 3.76 dB higher attenuation with optimum  $t_0$  at  $\Delta f_{sw}=50\text{kHz}$  compared with unmodified sawtooth modulating waveform (with  $t_0=0.5T_m$ ). Secondly, the higher  $f_m$  is, the lower difference between  $t_0$  and  $0.5T_m$  should be.

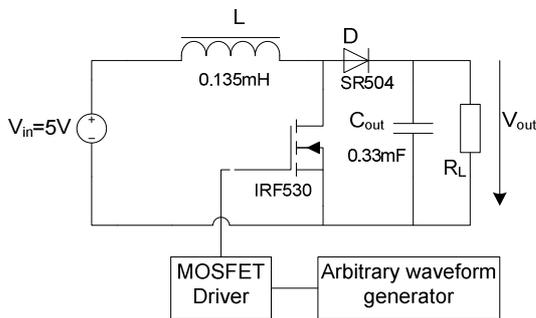
Optimum values of  $t_0$  for a given  $\Delta f_{sw}$  and  $f_m$  can be found from those curves or using our Matlab code. The optimum values of  $t_0$  give us a possibility to achieve the best attenuation drastically reducing AM effects. After applying optimum  $t_0$ , the spectrum of modulated  $i_L$  becomes more symmetrical with respect to the central switching frequency, as it is also shown in Fig.11.

## Experimental verifications

### Experimental setup

A frequency-modulated low power boost converter (Fig.12) is designed and built to test the theoretical calculations described above. The converter operating in CCM is tested in open loop mode. The input voltage of 5V is fed from a regulated DC source. Output resistive load is  $R_L=12\Omega$ . The nominal output voltage  $V_{out}=8\text{V}$  at  $D=0.5$ . The nominal switching frequency  $f_{sw}=100\text{kHz}$ .

To perform the frequency modulation, frequency modulated square waveform from an arbitrary waveform generator is fed into driver controlling the power MOSFET. All the modulation parameters, including  $t_0$ , can be set by the generator.

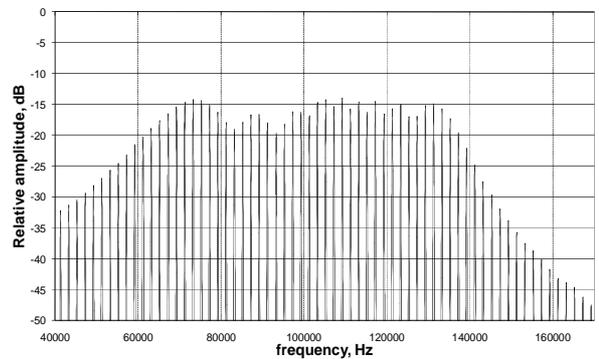


**Fig.12** Simplified schematic diagram of the experimental setup

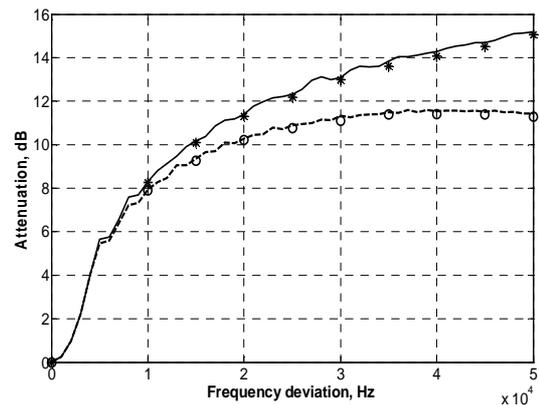
### Experimental results

Input current ripples are analyzed by the use of a spectrum analyzer (Agilent E4402B) with  $\text{RBW}=200\text{Hz}$ . The experimental inductor current spectrum for  $f_m=2\text{kHz}$ ,  $\Delta f_{sw}=40\text{kHz}$  and optimum  $t_0=0.27$  is shown in Fig.13. Attenuation  $A_I$  of maximum amplitude of unmodulated  $i_L$  spectrum both experimental and theoretical as a function of  $\Delta f_{sw}$  for modified and unmodified sawtooth modulating waveform is depicted in Fig.14.

To achieve the best attenuation theoretically obtained optimum values of  $t_0$  were used in our experiments. The comparison of the results prove that experimental results are in close agreement with the theoretical calculations.



**Fig.13** Experimental spectrum of modulated  $i_L$  with modified modulating sawtooth waveform. Modulation parameters:  $\Delta f_{sw}=40\text{kHz}$ ,  $f_m=2\text{kHz}$ ,  $f_{sw}=100\text{kHz}$ ,  $t_0=0.27T_m$



**Fig.14** Theoretical and experimental  $A_I$  as a function of  $\Delta f_{sw}$  for  $f_m=2\text{kHz}$ . (Solid line: theoretical  $A_I$  for modified sawtooth with optimum  $t_0$ ; dashed line: theoretical  $A_I$  for unmodified sawtooth with  $t_0=0.5T_m$ ; (\*) experimental  $A_I$  for modified sawtooth with optimum  $t_0$ ; (o) experimental  $A_I$  for unmodified sawtooth with  $t_0=0.5T_m$ )

## Conclusions

Analysis of the spectrum of frequency modulated boost converter input current causing conducted EMI has been presented in this paper. The analysis is based on theoretical calculations of spectra of modulated and unmodulated inductor current and attenuation of maximum spectrum amplitude of unmodulated one. During the analysis it was found out that the main reason for worsening the attenuation with increasing switching frequency deviation are amplitude modulation effects inherent in the input current of the boost converter. The amplitude modulation effects can be effectively neutralized by the modification of the modulating waveform, leading to reduction in the input current spectrum distortion and improvement of the attenuation. The theoretical calculations have been verified experimentally showing the attenuation up to 15 dB with modified modulating waveform.

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## References

1. Lin F., Chen D. Reduction of Power Supply EMI Emission by Switching Frequency Modulation // IEEE Trans. on Power Electronics. – 1994. - Vol.9, No.1. - pp. 132-137.
2. Gonzalez D., Balcells J., Santolaria A. Conducted EMI Reduction in Power Converters by Means of Periodic Switching Frequency Modulation // IEEE Trans. On Power Electronics. – 2007. - Vol.22, No.6. - pp. 2271-2281.
3. Jankovskis J., Stepins D., Pikulins D. Examination of different spread spectrum techniques for EMI suppression in dc/dc converters // Electronics and Electrical Engineering, 2008, No. 6(86), pp. 60-64.
4. Tse K., Chung H., Hui S. Comparative Study of Carrier-Frequency Modulation Techniques for Conducted EMI Suppression in PWM Converters // IEEE Trans. on Industrial

- Electronics. – 2002. - Vol. 49, No.3. - pp. 618-627.
5. Kuisma M., Jarvelainen T., Silventoinen P. Analyzing current ripple in variable frequency DC/DC Boost converter // IEEE 2007 Power Electronics Specialists conference, pp. 1535-1540.
  6. Balcells J., Gonzales D., Gago J., Satolaria A., Bunetel J.C.L., Magnon D., Brehaut S. Frequency modulation techniques for EMI reduction in SMPS // in Proc. 9th Europ. Conf. Power Electron. and Applications, EPE'05. – 2005. – P. 1 – 6.
  7. Gonzalez D., Bialasiewicz J.T., Balcells J. Wavelet-Based Performance Evaluation of Power Converters Operating with Modulated Switching Frequency // IEEE Trans. on Industrial Electronics. – 2008. - Vol.55, No.8. - pp. 3167-3176.
  8. Santolaria A., SSCG methods of EMI emissions reduction applied to switching power converters // Ph.D. dissertation, Electron. Eng. Dept., Polytechnic University of Catalonia, Barcelona, Spain, Jul. 2004.
  9. Mihalic F., Kos D. Reduced Conductive EMI in Switched-Mode DC-DC Power Converters without EMI Filters: PWM versus Randomized PWM // IEEE Trans. on Power Electronics. – 2006. - Vol.21, No.6. - pp. 1783-1794.
  10. Johnson, S. Yin, Y. Zane, R. Custom Spectral Shaping for EMI Reduction in Electronic Ballasts // IEEE 2004 Applied Power Electronics Conference, pp. 137-142.

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#### **D. Stepins. Improving EMI attenuation in frequency modulated power converters**

*The effect of frequency modulation on a power switching converter electromagnetic interference (EMI) attenuation is examined in this paper. A method known as “modified ramp” is applied for EMI reduction in boost converters and it is optimized in such a way to reduce EMI more effectively. The method is based on the use of a modified sawtooth modulating waveform with different slopes for the lower and upper halves of the frequency-modulation-generated sidebands. The usefulness of the method for boost converters is also verified experimentally by the use of a low power boost converter operating in continuous conduction mode and controlled via an arbitrary waveform generator. EMI attenuation up to 15 dB is achieved after using the modified sawtooth modulating waveform with optimum values of a parameter  $t_0$  controlling the slopes. Analysis of the results shows that the experiments are in a close agreement with the theoretical calculations. The optimum values of  $t_0$  are calculated using numerical analysis of EMI spectrum taking into account amplitude modulation effects. Influence of frequency modulation parameters on  $t_0$  is also discussed.*

#### **D. Stepins. Elektromagnētisko traucējumu uzlabošana frekvenču modulētos impulsu pārveidotājos**

*Šajā darbā tiek izpētīta frekvenču modulācijas ietekme uz impulsu pārveidotāju elektromagnētisko traucējumu (EMT) vājinājumu. Metode zināma kā „lauztais zagis” pielietotā boost pārveidotājā EMT samazināšanai un ir optimizēta efektīvākai EMT samazināšanai. Šī metode ir balstīta uz lauza zagveida modulācijas signāla pielietošanas. Šim modulācijas signālam ir dažādie stāvumi sānoslu kreisajai un labai daļām. Šīs metodes efektivitāte boost pārveidotājos ir arī pārbaudīta eksperimentāli izmantojot mazas jaudas paaugstinošo impulsu pārveidotāju vadāmo no signāla ģeneratora. 15 dB EMT vājinājums bija sasniegts izmantojot šo metodi ar optimālām parametra  $t_0$  vērtībām, kurš kontrolē stāvumu. Iegūto rezultātu analīze parāda, ka eksperimentālie rezultāti labi sakrīt ar teorētiskiem. Optimālas  $t_0$  vērtības ir aprēķinātas izmantojot EMT spektra skaitlisko analīzi ņemot vērā amplitūdas modulācijas efektus. Frekvenču modulācijas parametru ietekme uz  $t_0$  ir arī apskatīta.*

#### **Д. Степин. Улучшение ослабления электро-магнитных помех в импульсных преобразователях с модуляцией частоты коммутации**

*В данной работе исследуется влияние частотной модуляции на электромагнитные помехи (ЭМП) в импульсных преобразователях электрической энергии. Метод основанный на ломанном пилообразном сигнале применен для ослабления ЭМП в повышающем преобразователе (ПП) и оптимизирован для более эффективного ослабления ЭМП. Этот метод основан на использовании пилообразного модулирующего колебания, имеющего разную крутизну для левой и правой половины боковых полос. Эффективность данного метода в ПП также проверена экспериментально, используя повышающий импульсный преобразователь малой мощности. Ославление ЭМП в 15 дБ было достигнуто, при использовании пилообразного модулирующего колебания с оптимальными значениями параметра  $t_0$  регулирующего крутизну. Анализ полученных результатов показал, что эксперименты сходятся с теоретическими вычислениями..*